1. General description

Logic level N-channel MOSFET in an LFPAK56 (Power SO8) package using TrenchMOS technology. This product is designed and qualified for use in a wide range of power supply & motor control equipment.

2. Features and benefits

- Advanced TrenchMOS provides low $R_{DSon}$ and low gate charge
- Logic level gate operation
- Avalanche rated, 100% tested
- LFPAK provides maximum power density in a Power SO8 package

3. Applications

- Synchronous rectifier in LLC topology
- Chargers & adaptors with $V_{out} < 10$ V
- Fast charge & USB-PD applications
- Battery powered motor control
- LED lighting & TV backlight

4. Quick reference data

<table>
<thead>
<tr>
<th>Symbol</th>
<th>Parameter</th>
<th>Conditions</th>
<th>Min</th>
<th>Typ</th>
<th>Max</th>
<th>Unit</th>
</tr>
</thead>
<tbody>
<tr>
<td>$V_{DS}$</td>
<td>drain-source voltage</td>
<td>$T_j \geq 25$ °C; $T_j \leq 175$ °C</td>
<td>-</td>
<td>-</td>
<td>60</td>
<td>V</td>
</tr>
<tr>
<td>$I_D$</td>
<td>drain current</td>
<td>$V_{GS} = 5$ V; $T_{mb} = 25$ °C; Fig. 2</td>
<td>-</td>
<td>-</td>
<td>86</td>
<td>A</td>
</tr>
<tr>
<td>$P_{tot}$</td>
<td>total power dissipation</td>
<td>$T_{mb} = 25$ °C; Fig. 1</td>
<td>-</td>
<td>-</td>
<td>147</td>
<td>W</td>
</tr>
<tr>
<td>$T_j$</td>
<td>junction temperature</td>
<td></td>
<td>-55</td>
<td>-</td>
<td>175</td>
<td>°C</td>
</tr>
</tbody>
</table>

Static characteristics

- $R_{DSon}$ | drain-source on-state resistance | $V_{GS} = 10$ V; $I_D = 20$ A; $T_j = 25$ °C; Fig. 11 | - | 6  | 7.5 | mΩ  |

Dynamic characteristics

- $Q_G(tot)$ | total gate charge | $V_{GS} = 10$ V; $I_D = 20$ A; $V_{DS} = 48$ V; $T_j = 25$ °C; Fig. 13; Fig. 14 | - | 60.6 | - | nC  |
- $Q_{GD}$  | gate-drain charge | $V_{GS} = 5$ V; $I_D = 20$ A; $V_{DS} = 48$ V; $T_j = 25$ °C; Fig. 13; Fig. 14 | - | 9.7 | - | nC  |
Nexperia

PSMN7R5-60YL

N-channel 60 V, 7.5 mΩ logic level MOSFET in LFPAK56

<table>
<thead>
<tr>
<th>Symbol</th>
<th>Parameter</th>
<th>Conditions</th>
<th>Min</th>
<th>Typ</th>
<th>Max</th>
<th>Unit</th>
</tr>
</thead>
<tbody>
<tr>
<td>$E_{DS(AlS)}$</td>
<td>non-repetitive drain-source avalanche energy</td>
<td>$I_D = 86 , A; , V_{sup} \leq 60 , V; , R_{GS} = 50 , \Omega; , V_{GS} = 5 , V; , T_{j(init)} = 25 , ^\circ\text{C}; , unclamped; , \text{Fig. 4}$</td>
<td>-</td>
<td>-</td>
<td>76.5</td>
<td>mJ</td>
</tr>
</tbody>
</table>

[1] Single-pulse avalanche rating limited by maximum junction temperature of 175 °C.
[2] Refer to application note AN10273 for further information.

5. Pinning information

<table>
<thead>
<tr>
<th>Pin</th>
<th>Symbol</th>
<th>Description</th>
<th>Simplified outline</th>
<th>Graphic symbol</th>
</tr>
</thead>
<tbody>
<tr>
<td>1</td>
<td>S</td>
<td>source</td>
<td></td>
<td></td>
</tr>
<tr>
<td>2</td>
<td>S</td>
<td>source</td>
<td></td>
<td></td>
</tr>
<tr>
<td>3</td>
<td>S</td>
<td>source</td>
<td></td>
<td></td>
</tr>
<tr>
<td>4</td>
<td>G</td>
<td>gate</td>
<td></td>
<td></td>
</tr>
<tr>
<td>mb</td>
<td>D</td>
<td>mounting base; connected to drain</td>
<td>LFKAP56; Power-SO8 (SOT669)</td>
<td></td>
</tr>
</tbody>
</table>

6. Ordering information

<table>
<thead>
<tr>
<th>Type number</th>
<th>Package</th>
<th>Name</th>
<th>Description</th>
<th>Version</th>
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<tr>
<td>PSMN7R5-60YL</td>
<td>LFPAK56; Power-SO8</td>
<td>Plastic single-ended surface-mounted package (LFPAK56; Power-SO8); 4 leads</td>
<td>SOT669</td>
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7. Limiting values

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<tr>
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<th>Conditions</th>
<th>Min</th>
<th>Max</th>
<th>Unit</th>
</tr>
</thead>
<tbody>
<tr>
<td>$V_{DS}$</td>
<td>drain-source voltage</td>
<td>$T_j \geq 25 , ^\circ\text{C}; , T_j \leq 175 , ^\circ\text{C}$</td>
<td>-</td>
<td>60</td>
<td>V</td>
</tr>
<tr>
<td>$V_{DGR}$</td>
<td>drain-gate voltage</td>
<td>$R_{GS} = 20 , k\Omega$</td>
<td>-</td>
<td>60</td>
<td>V</td>
</tr>
<tr>
<td>$V_{GS}$</td>
<td>gate-source voltage</td>
<td>-20</td>
<td>20</td>
<td>V</td>
<td></td>
</tr>
<tr>
<td>$P_{tot}$</td>
<td>total power dissipation</td>
<td>$T_{mb} = 25 , ^\circ\text{C}; , \text{Fig. 1}$</td>
<td>-</td>
<td>147</td>
<td>W</td>
</tr>
<tr>
<td>$I_D$</td>
<td>drain current</td>
<td>$T_{mb} = 25 , ^\circ\text{C}; , V_{GS} = 5 , V; , \text{Fig. 2}$</td>
<td>-</td>
<td>86</td>
<td>A</td>
</tr>
<tr>
<td></td>
<td></td>
<td>$T_{mb} = 100 , ^\circ\text{C}; , V_{GS} = 5 , V; , \text{Fig. 2}$</td>
<td>-</td>
<td>61</td>
<td>A</td>
</tr>
<tr>
<td>$I_{DM}$</td>
<td>peak drain current</td>
<td>$T_{mb} = 25 , ^\circ\text{C}; , \text{pulsed; } t_p \leq 10 , \mu\text{s}; , \text{Fig. 3}$</td>
<td>-</td>
<td>346</td>
<td>A</td>
</tr>
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<td>Min</td>
<td>Max</td>
<td>Unit</td>
</tr>
<tr>
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<td>----------------------------</td>
<td>---------------------------------</td>
<td>------</td>
<td>------</td>
<td>------</td>
</tr>
<tr>
<td>$T_{stg}$</td>
<td>storage temperature</td>
<td></td>
<td>-55</td>
<td>175</td>
<td>°C</td>
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<tr>
<td>$T_j$</td>
<td>junction temperature</td>
<td></td>
<td>-55</td>
<td>175</td>
<td>°C</td>
</tr>
</tbody>
</table>

### Source-drain diode

| I$_S$    | source current             | $T_{mb} = 25$ °C                | -    | 86   | A    |
| I$_{SM}$ | peak source current        | pulsed; $t_p \leq 10$ µs; $T_{mb} = 25$ °C | -    | 346  | A    |

### Avalanche ruggedness

$E_{DS(AlS)}$ non-repetitive drain-source avalanche energy

$I_D = 86$ A; $V_{sup} \leq 60$ V; $R_{GS} = 50$ Ω; $V_{GS} = 5$ V; $T_{j(init)} = 25$ °C; unclamped; $V_{GS} \geq 5$ V; $T_{j(init)} = 25$ °C; unclamped; $E_{DS(AlS)} \leq 76.5$ mJ

[1] Single-pulse avalanche rating limited by maximum junction temperature of 175 °C.
[2] Refer to application note AN10273 for further information.

![Normalized total power dissipation as a function of mounting base temperature](image1)

**Fig. 1.** Normalized total power dissipation as a function of mounting base temperature

$$P_{der} = \frac{P_{tot}}{P_{tot(25^\circ C)}} \times 100\%$$

![Continuous drain current as a function of mounting base temperature](image2)

**Fig. 2.** Continuous drain current as a function of mounting base temperature

$V_{GS} \geq 5$ V
Fig. 3. Safe operating area; continuous and peak drain currents as a function of drain-source voltage

\[ T_{mb} = 25^\circ C, \; I_{DM} \text{ is a single pulse} \]

Fig. 4. Avalanche rating; avalanche current as a function of avalanche time

\[
\begin{align*}
(1) \; & T_{j(init)} = 25^\circ C; \\
(2) \; & T_{j(init)} = 150^\circ C; \\
(3) \; & \text{Repetitive Avalanche}
\end{align*}
\]

8. Thermal characteristics

<table>
<thead>
<tr>
<th>Symbol</th>
<th>Parameter</th>
<th>Conditions</th>
<th>Min</th>
<th>Typ</th>
<th>Max</th>
<th>Unit</th>
</tr>
</thead>
<tbody>
<tr>
<td>( R_{th(j-mb)} )</td>
<td>thermal resistance from junction to mounting base</td>
<td>Fig. 5</td>
<td>-</td>
<td>-</td>
<td>1.02</td>
<td>K/W</td>
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</tbody>
</table>
### Characteristics

#### Table 6. Characteristics

<table>
<thead>
<tr>
<th>Symbol</th>
<th>Parameter</th>
<th>Conditions</th>
<th>Min</th>
<th>Typ</th>
<th>Max</th>
<th>Unit</th>
</tr>
</thead>
<tbody>
<tr>
<td><strong>Static characteristics</strong></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>$V_{(BR)DSS}$</td>
<td>drain-source breakdown voltage</td>
<td>$I_D = 250 \mu A; V_{GS} = 0 , V; T_J = 25 ^\circ C$</td>
<td>60</td>
<td>-</td>
<td>-</td>
<td>V</td>
</tr>
<tr>
<td></td>
<td></td>
<td>$I_D = 250 \mu A; V_{GS} = 0 , V; T_J = -55 ^\circ C$</td>
<td>54</td>
<td>-</td>
<td>-</td>
<td>V</td>
</tr>
<tr>
<td>$V_{GS(th)}$</td>
<td>gate-source threshold voltage</td>
<td>$I_D = 1 , mA; V_{DS} = V_{GS}; T_J = 25 ^\circ C$; Fig. 9; Fig. 10</td>
<td>1.4</td>
<td>1.7</td>
<td>2.1</td>
<td>V</td>
</tr>
<tr>
<td></td>
<td></td>
<td>$I_D = 1 , mA; V_{DS} = V_{GS}; T_J = -55 ^\circ C$; Fig. 9</td>
<td>-</td>
<td>-</td>
<td>2.45</td>
<td>V</td>
</tr>
<tr>
<td></td>
<td></td>
<td>$I_D = 1 , mA; V_{DS} = V_{GS}; T_J = 175 ^\circ C$; Fig. 9</td>
<td>0.5</td>
<td>-</td>
<td>-</td>
<td>V</td>
</tr>
<tr>
<td>$I_{DSS}$</td>
<td>drain leakage current</td>
<td>$V_{DS} = 60 , V; V_{GS} = 0 , V; T_J = 175 ^\circ C$</td>
<td>-</td>
<td>-</td>
<td>500</td>
<td>$\mu A$</td>
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<tr>
<td></td>
<td></td>
<td>$V_{DS} = 60 , V; V_{GS} = 0 , V; T_J = 25 ^\circ C$</td>
<td></td>
<td>0.05</td>
<td>10</td>
<td>$\mu A$</td>
</tr>
<tr>
<td>$I_{GSS}$</td>
<td>gate leakage current</td>
<td>$V_{GS} = 16 , V; V_{DS} = 0 , V; T_J = 25 ^\circ C$</td>
<td>-</td>
<td>2</td>
<td>100</td>
<td>nA</td>
</tr>
<tr>
<td></td>
<td></td>
<td>$V_{GS} = -16 , V; V_{DS} = 0 , V; T_J = 25 ^\circ C$</td>
<td>-</td>
<td>2</td>
<td>100</td>
<td>nA</td>
</tr>
<tr>
<td>$R_{DSon}$</td>
<td>drain-source on-state resistance</td>
<td>$V_{GS} = 5 , V; I_D = 20 , A; T_J = 25 ^\circ C$; Fig. 11</td>
<td>-</td>
<td>6.8</td>
<td>8.7</td>
<td>m$\Omega$</td>
</tr>
<tr>
<td></td>
<td></td>
<td>$V_{GS} = 10 , V; I_D = 20 , A; T_J = 25 ^\circ C$; Fig. 11</td>
<td>-</td>
<td>6</td>
<td>7.5</td>
<td>m$\Omega$</td>
</tr>
<tr>
<td></td>
<td></td>
<td>$V_{GS} = 5 , V; I_D = 20 , A; T_J = 175 ^\circ C$; Fig. 12; Fig. 11</td>
<td>-</td>
<td>-</td>
<td>19.7</td>
<td>m$\Omega$</td>
</tr>
<tr>
<td><strong>Dynamic characteristics</strong></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>$Q_{G(tot)}$</td>
<td>total gate charge</td>
<td>$I_D = 20 , A; V_{DS} = 48 , V; V_{GS} = 5 , V$; T_J = 25 ^\circ C; Fig. 13; Fig. 14</td>
<td>-</td>
<td>31</td>
<td>-</td>
<td>nC</td>
</tr>
</tbody>
</table>

Fig. 5. Transient thermal impedance from junction to mounting base as a function of pulse duration
## Symbol | Parameter | Conditions | Min | Typ | Max | Unit
--- | --- | --- | --- | --- | --- | ---
$Q_{GS}$ | gate-source charge | $I_D = 20 A; V_{DS} = 48 V; V_{GS} = 10 V; T_J = 25 \, ^\circ C; \text{Fig. 13; Fig. 14}$ | - | 60.6 | - | nC
$Q_{GD}$ | gate-drain charge | $I_D = 20 A; V_{DS} = 48 V; V_{GS} = 5 V; T_J = 25 \, ^\circ C; \text{Fig. 13; Fig. 14}$ | - | 9 | - | nC
$C_{iss}$ | input capacitance | $V_{GS} = 0 V; V_{DS} = 25 V; f = 1 \, MHz; T_J = 25 \, ^\circ C; \text{Fig. 15}$ | - | 3435 | 4570 | pF
$C_{oss}$ | output capacitance | | - | 295 | 355 | pF
$C_{rss}$ | reverse transfer capacitance | | - | 150 | 205 | pF
$t_{d(on)}$ | turn-on delay time | $V_{DS} = 45 V; R_L = 2 \, \Omega; V_{GS} = 5 V; R_{G(extr)} = 5 \, \Omega; T_J = 25 \, ^\circ C$ | - | 17 | - | ns
$t_r$ | rise time | | - | 30 | - | ns
$t_{d(off)}$ | turn-off delay time | | - | 42 | - | ns
$t_f$ | fall time | | - | 26 | - | ns

### Source-drain diode

- $V_{SD}$: source-drain voltage
- $t_{rr}$: reverse recovery time
- $Q_r$: recovered charge

$V_{SD}$ = 20 A; $V_{GS} = 0 V; T_J = 25 \, ^\circ C; \text{Fig. 16}$

- $0.82$ | $1.2$ | V

- $I_S = 20 A; \text{d}I_S/\text{d}t = -100 \, \text{A/\mu s}; V_{GS} = 0 V; V_{DS} = 25 V; T_J = 25 \, ^\circ C$

- $24$ | - | ns

- $22.3$ | - | nC

### Figures

- **Fig. 6.** Output characteristics; drain current as a function of drain-source voltage; typical values
- **Fig. 7.** Drain-source on-state resistance as a function of gate-source voltage; typical values

$T_J = 25 \, ^\circ C; I_D = 20 A$
Fig. 8. Transfer characteristics; drain current as a function of gate-source voltage; typical values

\[ V_{DS} = 10\text{V} \]

Fig. 9. Gate-source threshold voltage as a function of junction temperature

\[ I_D = 1\text{mA}; V_{DS} = V_{GS} \]

Fig. 10. Sub-threshold drain current as a function of gate-source voltage

\[ T_J = 25^\circ\text{C}; V_{DS} = 5\text{V} \]

Fig. 11. Drain-source on-state resistance as a function of drain current; typical values

\[ T_J = 25^\circ\text{C}; t_p = 300\mu\text{s} \]
Fig. 12. Normalized drain-source on-state resistance factor as a function of junction temperature

\[ a = \frac{R_{DSon}}{R_{DSon}(25^\circ C)} \]

Fig. 13. Gate charge waveform definitions

Fig. 14. Gate-source voltage as a function of gate charge; typical values

\[ T_J = 25^\circ C; \; I_D = 20A \]

Fig. 15. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

\[ V_{GS} = 0V; \; f = 1MHz \]
Fig. 16. Source-drain (diode forward) current as a function of source-drain (diode forward) voltage; typical values

\[ V_{GS} = 0V \]
PSMN7R5-60YL
N-channel 60 V, 7.5 mΩ logic level MOSFET in LFPAK56

10. Package outline

Plastic single-ended surface-mounted package (LFPAK56; Power-SO8); 4 leads

Fig. 17. Package outline LFPAK56; Power-SO8 (SOT669)
11. Legal information

11.1 Data sheet status

<table>
<thead>
<tr>
<th>Document status</th>
<th>Product status</th>
<th>Definition</th>
</tr>
</thead>
<tbody>
<tr>
<td>Objective [short] data sheet</td>
<td>Development</td>
<td>This document contains data from the objective specification for product development.</td>
</tr>
<tr>
<td>Preliminary [short] data sheet</td>
<td>Qualification</td>
<td>This document contains data from the preliminary specification.</td>
</tr>
<tr>
<td>Product [short] data sheet</td>
<td>Production</td>
<td>This document contains the product specification.</td>
</tr>
</tbody>
</table>

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term “short data sheet” is explained in section “Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nexperia.com.

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